

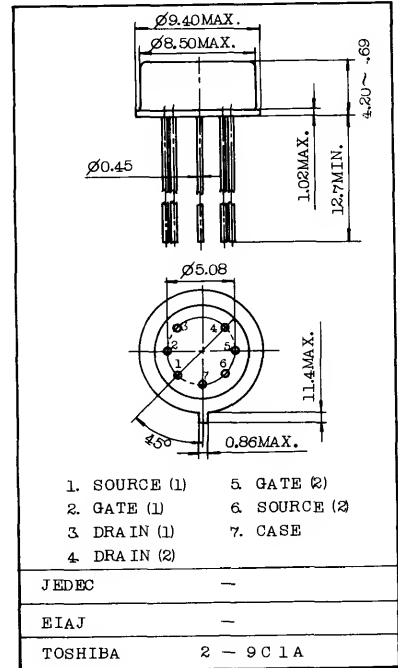
SILICON N CHANNEL JUNCTION DUAL TYPE (COMPLETELY SEPARATED TYPE)

2SK18
2SK18A

DIFFERENTIAL AMPLIFIER APPLICATIONS.

FEATURES:

- Low Offset : $V_{GS1} - V_{GS2} = 10\text{mV (Max.)}$
- Good Tracking
: $\Delta |V_{GS1} - V_{GS2}| / \Delta T_a = 20\mu\text{V}/^\circ\text{C (Max.)}$. (2SK18A)
- High Input Impedance : $I_G = -100\text{pA (Max.)}$
at $V_{DS} = 10\text{V}$, $I_D = 400\mu\text{A}$.
- Similar Characteristics as 2SK15.



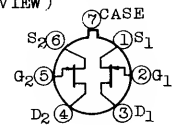
MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Gate-Drain Voltage	V_{GDS}	-40	V
Gate Current	I_G	10	mA
Drain Power Dissipation	P_D	200	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-65~150	$^\circ\text{C}$

Weight : 0.90g

PIN CONNECTION

(BOTTOM VIEW)



2SK18

2SK18A

ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
Gate Leakage Current	I_G	$V_{DS}=10V, I_D=400\mu A$	-	-	-0.1	nA	
Gate-Drain Breakdown Voltage	$V(BR)_{GDS}$	$V_{DS}=0, I_G=-0.1mA$	-40	-	-	V	
Drain Current	I_{DSS} (Note)	$V_{DS}=10V, V_{GS}=0$	0.45	-	2.8	mA	
Gate-Source Cut-off Voltage	$V_{GS(OFF)}$ (Note)	$V_{DS}=10V, I_D=0.1\mu A$	-0.65	-	-3.5	V	
Forward Transfer Admittance	$ y_{fs} $ (Note)	$V_{DS}=10V, V_{GS}=0, f=1kHz$	800	-	3000	μS	
Input Capacitance	C_{iss}	$V_{GD}=0, f=1MHz$	-	4.5	6.0	pF	
Reverse Transfer Capacitance	C_{rss}	$V_{DS}=0, V_{GD}=-10V, f=1MHz$	-	2.0	2.5	pF	
Drain Current Ratio	$I_{DSS(small)}/I_{DSS(large)}$	$V_{DD}=10V, V_{GS}=0$	0.9	-	1.0		
Forward Transfer Admittance Ratio	$ y_{fs} $ (S) $ y_{fs} $ (L)	$V_{DS}=10V, V_{GS}=0, f=1kHz$	0.9	-	1.0		
Differential Gate-Source Voltage	$ V_{GS1}-V_{GS2} $	$V_{DG}=10V, I_D=400\mu A$	-	-	10	mV	
		$V_{DG}=10V, I_D=200\mu A$	-	-	10	mV	
		$V_{DG}=10V, I_D=50\mu A$	-	-	10	mV	
Gate-Source Voltage Differential Drift	2SK18	$d V_{GS1}-V_{GS2} /Ta$	$V_{DS}=10V, I_D=200\mu A$ $Ta=0 \sim 60^\circ C$	-	-	100	$\mu V/^\circ C$
	2SK18A			-	-	20	

Note: According to the value of I_{DSS1} , $V_{GS(OFF)1}$, $V_{GS(OFF)1}$, and $|y_{fs}|_1$, the 2SK18 series are classified as follows.

CLASSIFICATIONS	I_{DSS1} (mA)		$V_{GS(OFF)1}$ (V)		$ y_{fs} _1$ (μS)	
	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.
2SK18-R, 2SK18A-R	0.45	0.90	-0.65	-1.8	800	1900
2SK18-O, 2SK18A-O	0.80	1.60	-0.90	-2.5	1000	2300
2SK18-Y, 2SK18A-Y	1.40	2.80	-1.40	-3.5	1300	3000